

Mono Crystalline Silicon Solar Cell

Physical Characteristics

Dimension 156.0 mm x 156.0 mm \pm 0.5 mm

Diagonal 200 mm ± 1.0 mm (round chamfers)

Thickness (Si) 200µm ± 30µm

Front Three silver busbars, anisotropically texturized surface with

dark blue silicon nitride anti-reflection coating.

Back Full-surface aluminum BSF, Silver / Aluminum soldering pads.



Electrical Characteristics

Efficiency Code	2000	1990	1980	1970	1960	1950	1940
Efficiency (%)	≧20.0	19.9	19.8	19.7	19.6	19.5	19.4
Pmax (W)	<u>≥</u> 4.777	4.753	4.729	4.706	4.682	4.658	4.634
Vmpp (V)	0.544	0.543	0.542	0.541	0.540	0.538	0.537
Impp (A)	8.820	8.776	8.738	8.710	8.681	8.666	8.631
Voc (V)	0.644	0.643	0.642	0.641	0.640	0.639	0.639
Isc (A)	9.310	9.307	9.275	9.243	9.221	9.200	9.158

^{*}Data under standard testing conditions (STC): 1000 W/M², AM1.5, 25°C. All figures bear ±5% of tolerance. The measurement of cell is calibrated by Fraunhofer ISE. Model name = Product code + Efficiency code. Example: B156S1D2B-1960

Typical Temperature Coefficients

Voltage	-1.92 mV/K
Current	+5.16 mA/K
Power	-0.34%/K

Quality

BIG SUN's Quality system is certified by ISO 9001, Environmental Management System by ISO 14001, Occupational Health and Safety Management System by OHSAS 18001.

BIG SUN Energy Technology Inc.

No. 458-9, Sinsing Rd., Hukou Township,

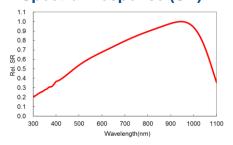
Hsinchu County 30353, Taiwan

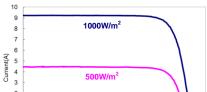
T: +886 3 598-0288

F: +886 3 598-0299

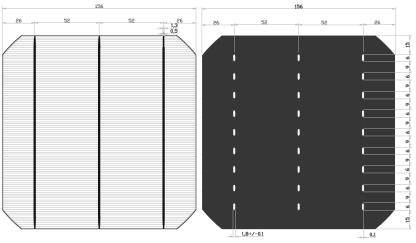
E: sales@bigsun-energy.com

Spectral Response (SR)





IV Curve of Cell: 1960



Subject to specification changes without notification.

0.6